

March 1993 Revised April 1999

74VHC573 Octal D-Type Latch with 3-STATE Outputs

General Description

The VHC573 is an advanced high speed CMOS octal latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a latch enable input (LE) and an Output Enable input ($\overline{\text{OE}}$). When the $\overline{\text{OE}}$ input is HIGH, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This cir-

cuit prevents device destruction due to mismatched supply and input voltages.

Features

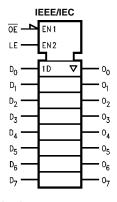
- High Speed: $t_{PD} = 5.0$ ns (typ) at $V_{CC} = 5V$
- High Noise Immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (Min)
- Power Down Protection is provided on all inputs
- Low Noise: V_{OLP} = 0.6V (typ)
- Low Power Dissipation: $I_{CC} = 4 \mu A \text{ (Max)} @ T_A = 25^{\circ}C$
- Pin and function compatible with 74HC573

Ordering Code:

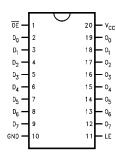
Order Number	Package Number	Package Description
74VHC573M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHC573SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC573MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC573N	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
D ₀ –D ₇	Data Inputs
LE	Latch Enable Input
ŌĒ	3-STATE Output Enable Input
O ₀ -O ₇	3-STATE Outputs

Functional Description

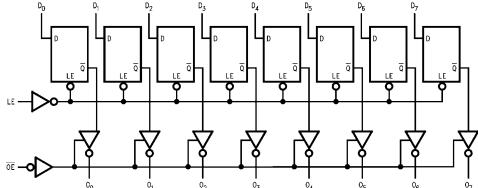
The VHC573 contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the $\mathbf{D}_{\mathbf{n}}$ inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs, a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable (\overline{OE}) input. When \overline{OE} is LOW, the buffers are enabled. When \overline{OE} is HIGH the buffers are in the high impedance mode, but, this does not interfere with entering new data into the latches.

Truth Table

	Outputs		
ŌE	LE	D	O _n
L	Н	Н	Н
L	Н	L	L
L	L	X	O ₀
Н	X	X	Z

- H = HIGH Voltage Level L = LOW Voltage Level
- X = Immaterial
- Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +7.0VDC Input Voltage (V_{IN}) -0.5V to +7.0V DC Output Voltage (V_{OUT}) -0.5V to V_{CC} +0.5V Input Diode Current (I_{IK}) -20 mA Output Diode Current ±20 mA DC Output Current (I_{OUT}) ±25 mA DC V_{CC}/GND Current (I_{CC}) $\pm 75~\text{mA}$ Storage Temperature (T_{STG}) -65°C to +150°C

Lead Temperature (T_L)

(Soldering, 10 seconds)

Recommended Operating Conditions (Note 2)

Input Rise and Fall Time (t_r, t_f)

$$\begin{split} \text{V}_{\text{CC}} = 3.3 \text{V} \pm 0.3 \text{V} & 0 \sim 100 \text{ ns/V} \\ \text{V}_{\text{CC}} = 5.0 \text{V} \pm 0.5 \text{V} & 0 \sim 20 \text{ ns/V} \end{split}$$

Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

Note 2: Unused inputs must be held HIGH or LOW They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC} T _A = 25°C		$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units	Conditions			
Oyillboi		(V)	Min	Тур	Max	Min	Max	Omico	Conditions	
V _{IH}	HIGH Level Input	2.0	1.50			1.50		V		
	Voltage	3.0 - 5.5	0.7 V _{CC}			0.7 V _{CC}		V		
V _{IL}	LOW Level Input	2.0			0.50		0.50	V		
	Voltage	3.0 - 5.5			$0.3\mathrm{V}_{\mathrm{CC}}$		$0.3 V_{\rm CC}$	V		
V _{OH}	HIGH Level Output	2.0	1.9	2.0		1.9			$V_{IN} = V_{IH}$	
	Voltage	3.0	2.9	3.0		2.9		V	or V _{IL}	$I_{OH} = -50 \mu A$
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		$I_{OH} = -4 \text{ mA}$
		4.5	3.94			3.80		V		$I_{OH} = -8 \text{ mA}$
V _{OL}	LOW Level Output	2.0		0.0	0.1		0.1		$V_{IN} = V_{IH}$	
	Voltage	3.0		0.0	0.1		0.1	V	or V _{IL}	$I_{OL} = 50 \mu A$
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V	1	I _{OL} = 4 mA
		4.5			0.36		0.44	V		$I_{OL} = 8 \text{ mA}$
l _{oz}	3-STATE Output	5.5			±0.25		±2.5	μΑ	$V_{IN} = V_{IH} c$	r V _{IL}
	Off-State Current								$V_{OUT} = V_{CC}$ or GND	
I _{IN}	Input Leakage Current	0 – 5.5			±0.1		±1.0	μΑ	V _{IN} = 5.5V or GND	
I _{CC}	Quiescent Supply Current	5.5			4.0		40.0	μΑ	$V_{IN} = V_{CC}$	or GND

260°C

Noise Characteristics

Symbol	Parameter	V _{CC}	T _A =	25°C	Units	Conditions	
Зуппон	Farameter	(V)	Тур	Limits	Ullits		
V _{OLP} (Note 3)	Quiet Output Maximum Dynamic V _{OL}	5.0	0.9	1.2	V	$C_L = 50 \text{ pF}$	
V _{OLV} (Note 3)	Quiet Output Minimum Dynamic V _{OL}	5.0	-0.8	-1.0	V	$C_L = 50 \text{ pF}$	
V _{IHD} (Note 3)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	$C_L = 50 \text{ pF}$	
V _{ILD} (Note 3)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	$C_L = 50 \text{ pF}$	

Note 3: Parameter guaranteed by design.

AC Electrical Characteristics

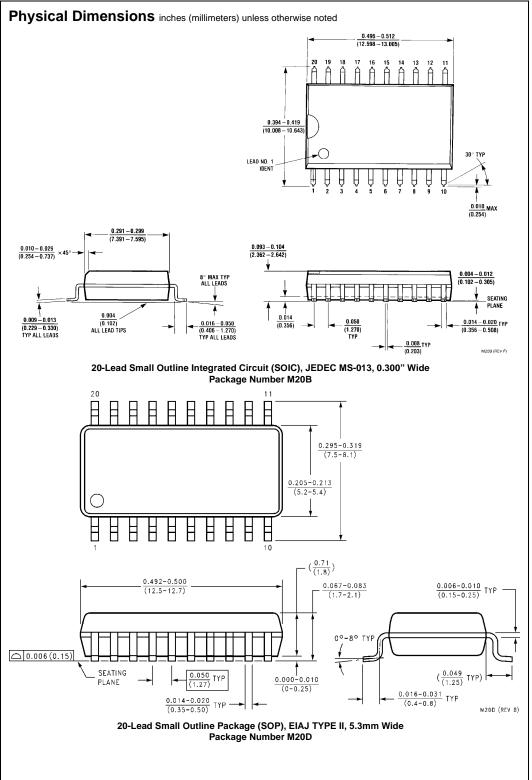
Symbol	Parameter	V _{cc}	T _A = 25°C		T _A = -40°	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Conditions		
Symbol	Farameter	(V)	Min	Тур	Max	Min	Max	Units	Conu	itions
t _{PLH}	Propagation Delay	3.3 ± 0.3		7.6	11.9	1.0	14.0	ns		C _L = 15 pF
t _{PHL}	Time (LE to O _n)			10.1	15.4	1.0	17.5	115		$C_L = 50 pF$
		5.0 ± 0.5		5.0	7.7	1.0	9.0	ns		$C_L = 15 pF$
				6.5	9.7	1.0	11.0	115		$C_L = 50 pF$
t _{PLH}	Propagation Delay	3.3 ± 0.3		7.0	11.0	1.0	13.0			C _L = 15 pF
t _{PHL}	Time (D-O _n)			9.5	14.5	1.0	16.5	ns		C _L = 50 pF
		5.0 ± 0.5		4.5	6.8	1.0	8.0	115		$C_L = 15 pF$
				6.0	8.8	1.0	10.0			C _L = 50 pF
t _{PZL}	3-STATE Output	3.3 ± 0.3		7.3	11.5	1.0	13.5	ns	$R_L = 1 k\Omega$	C _L = 15 pF
t _{PZH}	Enable Time			9.8	15.0	1.0	17.0	115	$C_{L} = 50 \text{p}$	$C_L = 50 pF$
		5.0 ± 0.5		5.2	7.7	1.0	9.0	ns		$C_L = 15 pF$
				6.7	9.7	1.0	11.0	115		C _L = 50 pF
t _{PLZ}	3-STATE Output	3.3 ± 0.3		10.7	14.5	1.0	16.5	ns	$R_L = 1 k\Omega$	C _L = 50 pF
t _{PHZ}	Disable Time	5.0 ± 0.5		6.7	9.7	1.0	11.0	115		$C_L = 50 pF$
toslh	Output to Output Skew	3.3 ± 0.3			1.5		1.5	ns	(Note 4)	C _L = 50 pF
t _{OSHL}		5.0 ± 0.5			1.0		1.0	115		$C_L = 50 pF$
C _{IN}	Input Capacitance			4	10		10	pF	V _{CC} = Open	•
C _{OUT}	Output Capacitance			6				pF	$V_{CC} = 5.0V$	
C _{PD}	Power Dissipation			29				pF	(Note 5)	
	Capacitance									

 $\textbf{Note 4:} \ \ \text{Parameter guaranteed by design.} \ \ t_{\text{OSLH}} = |t_{\text{PLH max}} - t_{\text{PLH min}}|; \ t_{\text{OSHL}} = |t_{\text{PHL max}} - t_{\text{PHL min}}|$

Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC} /8 (per Latch). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD} (total) = 21 + 8n.

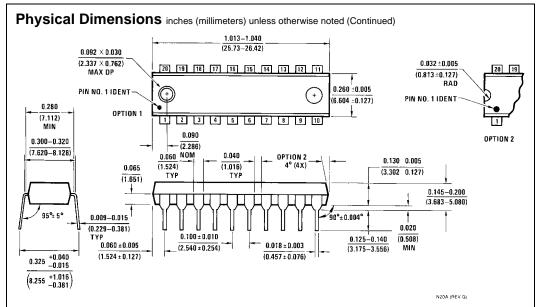
AC Operating Requirements

Symbol	Parameter	V _{cc}	T _A = 25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
Syllibol		(V)	Min	Тур	Max	Min	Max	Oille
t _w (H)	Minimum Pulse	3.3 ± 0.3	5.0			5.0		ns
$t_w(L)$	Width (LE)	5.0 ± 0.5	5.0			5.0		115
t _S	Minimum Setup Time	3.3 ± 0.3	3.5			3.5		ns
		5.0 ± 0.5	3.5			3.5		115
t _H	Minimum Hold Time	3.3 ± 0.3	1.5			1.5		ns
		5.0 ± 0.5	1.5			1.5		115



Physical Dimensions inches (millimeters) unless otherwise noted (Continued) -0.20 و2ا 7.72 4.16 6,4 4.4±0.1 -B-3,2 10.42 PIN #1 IDENT. LAND PATTERN RECOMMENDATION O.1 C ALL LEAD TIPS SEE DETAIL A -0.90^{+0.15} 0.09-0.20 0.1±0.05 0.65 0.19-0.30 | \$\P\$ | 0.10\P\$ | A P\$ | C\$ | -12.00° R0.09min GAGE PLANE DIMENSIONS ARE IN MILLIMETERS NOTES: 0.25 SEATING PLANE A. CONFORMS TO JEDEC REGISTRATION MID-153, VARIATION AC, REF NOTE 6, DATE $7/93.\,$ -0.6±0.1-R0.09mln -1.00 B. DIMENSIONS ARE IN MILLIMETERS. C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIONS. DETAIL A D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20



20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N20A

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